

## Supporting Information

### Application of dandelion-like $\text{Sm}_2\text{O}_3/\text{Co}_3\text{O}_4/\text{rGO}$ in high performance supercapacitors

#### S1: Synthesis of $\text{Sm}_2\text{O}_3/\text{Co}_3\text{O}_4/\text{NF}$ composite electrode material

0.75 mmol (0.333 g) of  $\text{Sm}(\text{NO}_3)_3 \cdot 6\text{H}_2\text{O}$ , 0.75 mmol (0.218 g) of  $\text{Co}(\text{NO}_3)_2 \cdot 6\text{H}_2\text{O}$ , and 1 mmol (0.060 g) of urea were added to 15 mL of distilled water and stirred vigorously with a magnetic stirrer for 1 h. The mixture was then transferred to a 25 mL tetrafluoroethylene lined autoclave containing a clean nickel foam (NF), and the reaction was carried out at a high temperature of 180 °C for 9 h. After completion of the reaction, the autoclave cooled to room temperature. The  $\text{Sm}_2\text{O}_3/\text{Co}_3\text{O}_4/\text{NF}$  precursor was repeatedly washed with deionized water and ethanol. The washed precursor was then dried at 60 °C for 8 h in an oven. Finally, the solid was annealed at 300 °C for 2 h in a muffle furnace to obtain the  $\text{Sm}_2\text{O}_3/\text{Co}_3\text{O}_4/\text{NF}$  composite electrode material.

#### S2: Synthesis of $\text{Co}_3\text{O}_4/\text{rGO}/\text{NF}$ composite electrode material

Dissolve 0.75 mmol of  $\text{Co}(\text{NO}_3)_2 \cdot 6\text{H}_2\text{O}$  and 1 mmol of urea in 7.5 mL of deionized water. Stir the mixture using a magnetic stirrer for 1 h to form a homogeneous solution. Then, 7.5 mL of a graphene oxide suspension with a concentration of 2  $\text{mg} \cdot \text{mL}^{-1}$  was added to the solution, followed by stirring for an additional 1 h. The treated NF and the mixed solution were then placed in a polytetrafluoroethylene high-pressure reactor and reacted at 180 °C for 9 h in an oven. The precursor was washed with ethanol and deionized water, followed by drying at 60 °C for 8 h. Finally, anneal the sample in a muffle furnace at 300 °C for 2 h to produce the  $\text{Co}_3\text{O}_4/\text{rGO}/\text{NF}$  composite electrode material.

#### S3: Synthesis of $\text{Sm}_2\text{O}_3/\text{rGO}/\text{NF}$ composite electrode material

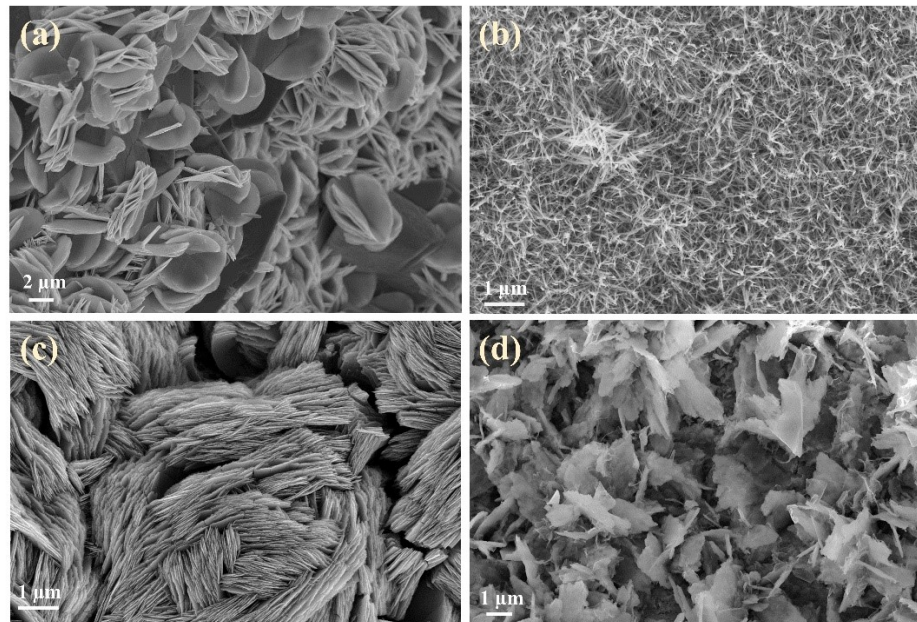
A homogeneous solution was obtained by dissolving 0.75 mmol  $\text{Sm}(\text{NO}_3)_3 \cdot 6\text{H}_2\text{O}$  and 1 mmol urea in 7.5 ml distilled water and stirring magnetically for 1 h. The graphene solution (7.5 mL, 2  $\text{mg} \cdot \text{mL}^{-1}$ ) was mixed with the above solution and stirred

vigorously for 1 h. The cleaned NF was transferred with the solution into a 25 mL tetrafluoroethylene-lined autoclave, heated at 180 °C for 9 h, and then cooled naturally to room temperature. The  $\text{Sm}_2\text{O}_3/\text{rGO}/\text{NF}$  precursor was then washed several times with ethanol and distilled water and dried at 60 °C for 8 h. The  $\text{Sm}_2\text{O}_3/\text{rGO}/\text{NF}$  precursor was then annealed in a muffle furnace at 300 °C for 2 h to obtain the  $\text{Sm}_2\text{O}_3/\text{rGO}/\text{NF}$  composite electrode material.

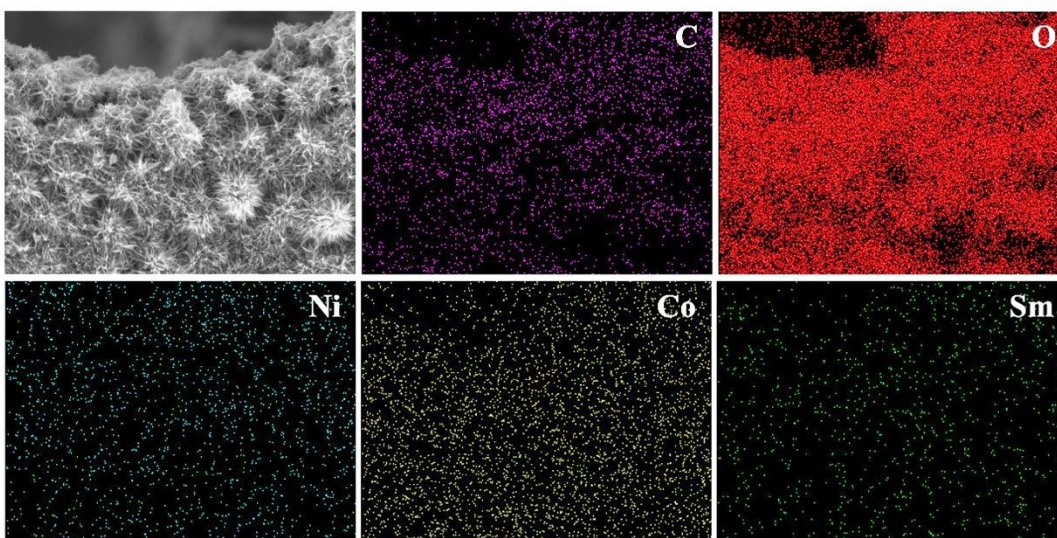
#### **S4: Synthesis of rGO/NF composite electrode material**

0.75 mmol of  $\text{Sm}(\text{NO}_3)_3 \cdot 6\text{H}_2\text{O}$  and 1 mmol of urea were mixed in 7.5 ml of distilled water. The solution and the cleaned nickel foam were then transferred to a 25 mL tetrafluoroethylene-lined autoclave and heated at 180 °C for 9 h. The rGO/NF precursor was washed with ethanol and deionized water and then dried in an oven at 60 °C for 8 h. Finally, it was annealed at 300 °C for 2 h in a muffle furnace to obtain the rGO/NF composite electrode material.

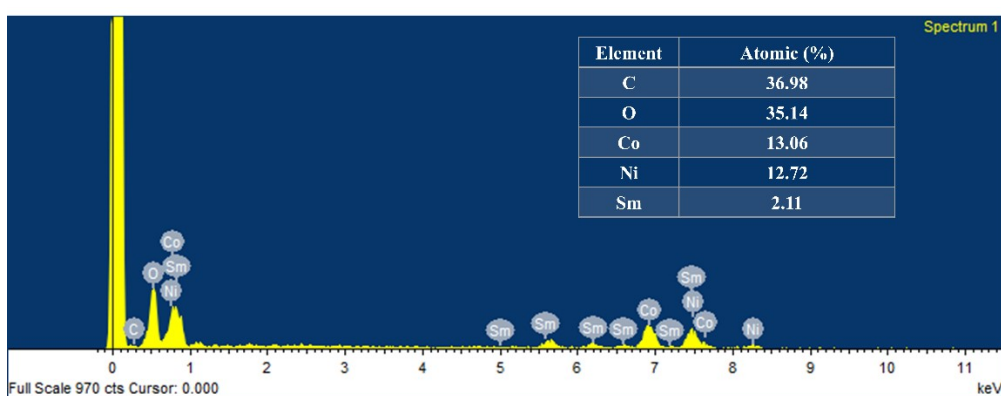
## **Results and discussion**



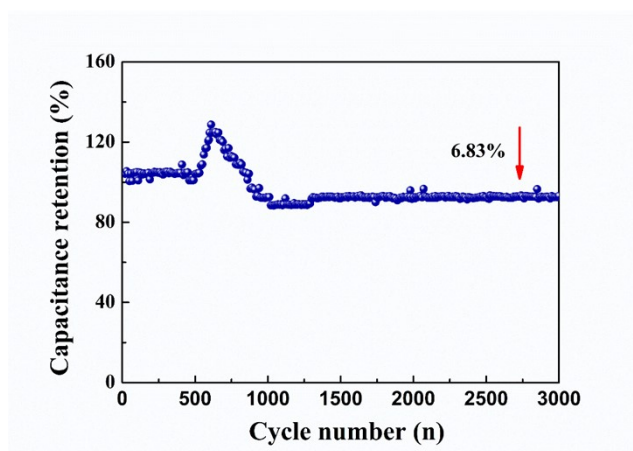
**Fig. S1 The SEM images of various materials: (a)  $\text{Co}_3\text{O}_4/\text{NF}$ , (b) CGN, (c)  $\text{Sm}_2\text{O}_3/\text{NF}$ , and (d) SCN**



**Fig. S2** EDS elemental mapping images of the composite (C, O, Ni, Co, and Sm)



**Fig. S3** EDS of SCGN



**Fig. S4** The capacitance retention at a current density of  $10 \text{ A} \cdot \text{g}^{-1}$  for 3000 cycles.

Table S1 Comparison of electrochemical performances of SCGN electrode in our work with previous.

Materials	Specific capacitance	capacitance retention (%)	Stability (%)	Current density	Refs.
Co <sub>3</sub> O <sub>4</sub> @MnO <sub>2</sub> composites	671 F·g <sup>-1</sup> at 1.0 A·g <sup>-1</sup>	84% (1 to 10 A·g <sup>-1</sup> )	95.2% (2000 cycles)	1 A·g <sup>-1</sup>	1
Co <sub>3</sub> O <sub>4</sub> -CeO <sub>2</sub> composites	1288.3F·g <sup>-1</sup> at 2.5 A·g <sup>-1</sup>	80.4% (1 to 6 A·g <sup>-1</sup> )	98% (6000 cycles)	4 A·g <sup>-1</sup>	2
Co <sub>3</sub> O <sub>4</sub> /NF composites	2053.1 F·g <sup>-1</sup> at 1.0 A·g <sup>-1</sup>	54.2% (1 to 40·A g <sup>-1</sup> )	93.3% (10000 cycles)	2 A·g <sup>-1</sup>	3
SmN-RGO composites	268 F·g <sup>-1</sup> at 2.0 A·g <sup>-1</sup>	----	99% (4000 cycles)	2 A·g <sup>-1</sup>	4
SmWO <sub>4</sub> composites	326 F·g <sup>-1</sup> at 2.0 mV·s <sup>-1</sup>	47% (1 to 16 A·g <sup>-1</sup> )	89.9% (3000 cycles)	20A·g <sup>-1</sup>	5
SmCoO <sub>3</sub> /rGO composite	69.3 F·g <sup>-1</sup> at 1.0 A g <sup>-1</sup>	----	74.28% (15000 cycles)	1 A·g <sup>-1</sup>	6
Sm <sub>2</sub> O <sub>3</sub> /Co <sub>3</sub> O <sub>4</sub> /rGO composites	3448 F·g <sup>-1</sup> at 1 A·g <sup>-1</sup>	44.8% (1 to 20 A·g <sup>-1</sup> )	93.2% (3000 cycles)	10 A·g <sup>-1</sup>	This work

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## References